

YJ Planar Fast Recovery Diode Die Specification

600V 15A, Fast recovery diode die based on silicon planar process
Part No.:LBDB5T600SS-330A

Main Products Characterstics

Maximum Ratings

Static Electrical Characteristics (Ta = 25°C)

Device Schematics and Outline Drawing

- Die Thickness
- Die Size *
- Top Metal Pad
- Active Area
- Top Metal
- Back Metal
- Note: 1 *: Cutting street width is around 40um

Important Notice